**IECQ-CECC** 

COMPONENT

QC 88000-C004

**ISSUE 1** 

### SPECIFICATION

March 2007

### Component Specification For Ceramic Hermetically Sealed High Speed Logic Gate High CMR Transistor Optocouplers



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This Component Specification is based upon the requirements of IEC Publication QC 001002-2, and has been prepared by:

Isocom Ltd Hutton Close Crowther Industrial Estate Washington Tyne and Wear NE38 0AH

Tel: +44 0191 4166 546 Fax: +44 0191 4155 055

and published under the authority of:

BSI Product Services Maylands Avenue Hemel Hempstead Hertfordshire HP2 4SQ United Kingdom

#### AMENDMENT RECORD

No previous issue.

#### REQUIREMENTS

The requirements for IECQ-CECC Component Specifications as detailed in QC 001002-2 Amendment 1 clause 5.4 are satisfied by the following data sheet.

It should note that IECQ-CECC are not responsible for manufacturers declarations made in data sheets which fall outside the limits of approved detailed in IECQ-CECC certificates.

This Component Specification is intended for use with applicable IECQ-CECC Assessment Specifications. Eg: QC 88000-A001

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## <u>Ceramic Hermetically Sealed High Speed Logic Gate</u> <u>High CMR Transistor Optocouplers</u>

- 6N134
- **CD650**
- CD651
- CH350

### **Features**

- Release to IECQ-CECC
- Hermetically Sealed
- High Density Packaging
- 1500V DC withstand Test Voltage
- Low Input Requirements
- High Current Transfer Ratio

- CS600
- CSM169
- CSM1600
- MC600

### **Applications**

- Military, high reliability system
- Medical instruments
- Mos, Cmos Applications
- Logic Interfacing
- Data Transmission
- Transportation

### **Description**

These devices are single, dual and quad, hermetically sealed optocouplers. The products are capable of operation and storage over the full military and space temperature range. Each channel is composed of a light emitting diode, optically coupled to an integrated high gain photon detector. The high gain output features an open collector output providing both lower saturation voltage and higher signalling speed. Package styles for these devices include 8 pin, 16 pin, 16 pin flat pack, leadless 6 pin and hybrid 5 pin, with surface mount, butt cut and gull wing options available.

The same electrical die, assembly processes and materials are used for each channel of each device shown below. Therefore absolute maximum ratings, recommended operating conditions, electrical specifications and performance characteristics are identical for all units. Any exceptions, due to packaging variations and limitations, are as noted.

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## **Selection Guide Package Styles and Configuration Options**

Package	16 pin DIP	8 pin DIP	6 pin DIP	16 pin Flat Pack	6 Pad LCCC	6 pin Metal Can TO-5
Lead Style						
Channels	2	1/2	1	4	1	1
Common Channel Wiring						
Isocom Part Numbers and Options						
	6N134	CS600				MC600
Commercial		CD650/651	CH350	CSM169	CSM1600	
	6N134/L2	CS600/L2				MC600/L2
Defense Level		CD650/651/L2	CH350/L2	CSM169/L2	CSM1600/L	
Space Level	6N134/L2S	CS600/L2S CD650/651/L2S	CH350/L2S	CSM169/L2S	CSM1600/L2	MC600/L2S
Standard Gold Plate Finish	Gold Plate	Gold Plate	Gold Plate	Gold Plate	Gold Plate	Gold Plate
Solder Dipped	Option 20	Option 20	Option 20			
Butt Cut/Gold Plate	Option 10	Option 10	Option 10			
Gull Wing/Soldered	Option 30	Option 30	Option 30			
Crew Cut/Gold Plate	Option 60	Option 60	Option 60			

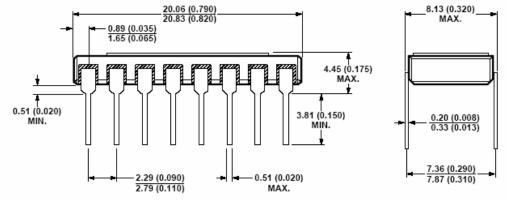
### **Functional Diagrams**

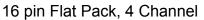
CH350	CS600	CD650/651	6N134	CSM169	CSM1600
1	1 Channel	2 Channel	2 Channel	4 Channel	1 Channel
Channel					
5 4 3 		8765 <u>22</u> 1234	16 15 14 13 12 11 10 9 <u>Å</u> <u>K1</u> 1 2 3 4 5 6 7 8	16 15 14 13 12 11 10 9 <u>* Â Â Â Â</u> <u>* 8</u> <u>* 8</u> <del>* 8</del> <del>* 100</del> <del>* 1000000000000000000000000000000000000</del>	
MC600					
1					
Channel					

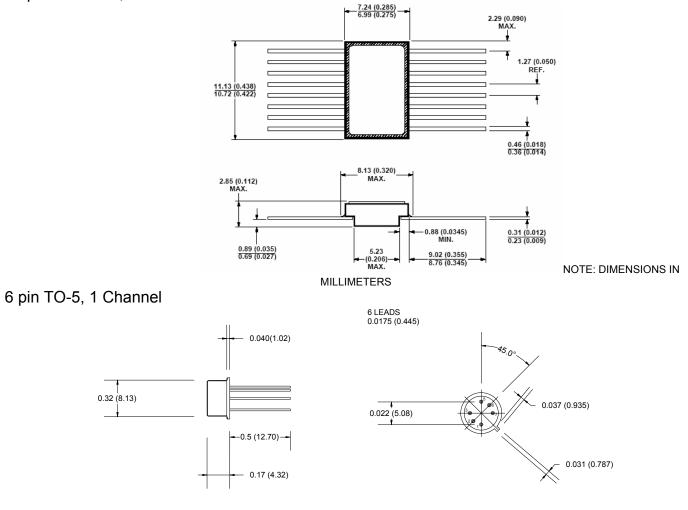
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### **Outline Drawings**

16 pin DIP, 4 Channel

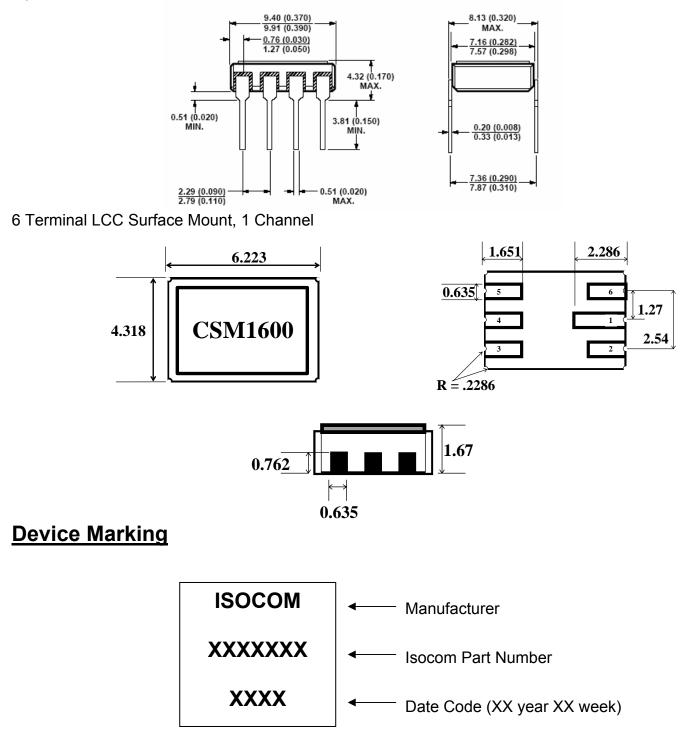






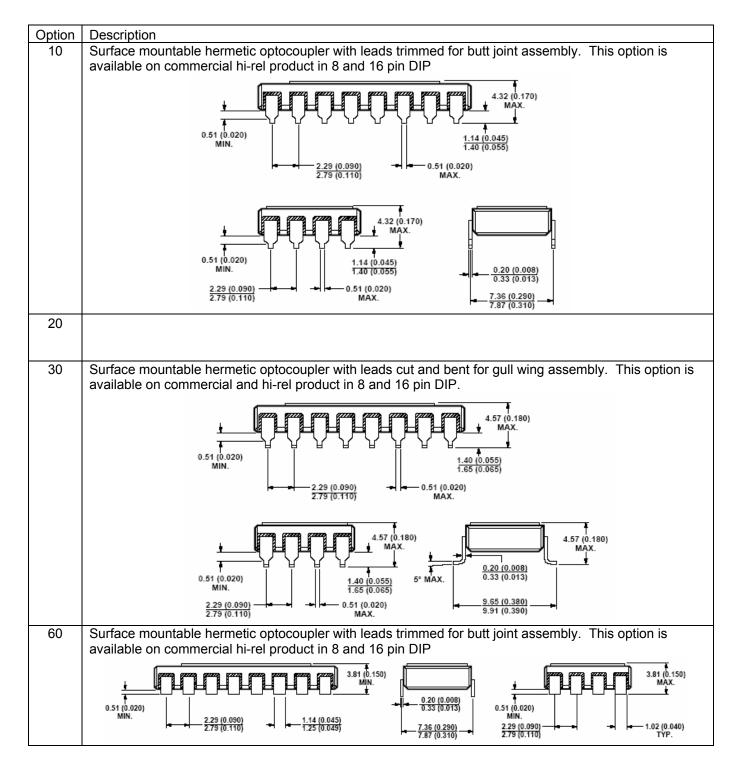
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8 pin DIP 1 and 2 Channel



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#### Hermetic Optocoupler Options



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## **Absolute Maximum Ratings**

Storage Temperature	-65°C to +150°C
Operating Temperature	-55°C to +125°C
Lead Soldering Temperature	260C for 10S, 1.6mm below seating plane where appropriate

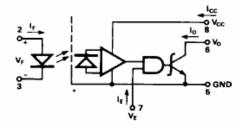
#### **Input Diode**

Peak Forward Current	40mA	$I_F (\leq 1 \text{ mS duration})$
Average Forward Current	20mA	l <sub>F</sub>
Reverse Voltage	5V	V <sub>R</sub>
Power Dissipation	35mW	

#### **Output Detector**

Supply Voltage	7V	V <sub>CC</sub> (1minute maximum)
Current	25mA	l <sub>o</sub>
Collector Power Dissipation	40mW	
Voltage	7V	V <sub>o</sub> (See note 1)

### **Single Channel Schematic**



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# $\frac{\text{Electrical Characteristics}}{T_{A} = -55^{\circ}\text{C to } +125^{\circ}\text{C U.O.S.}}$

All typical values at  $V_{CC}$  = 5V,  $T_A$  = 25°C (each channel where appropriate).

Parameter	Symbol	Test Conditions	Device	Min	Туре	Max	Units
High Level Output Current (See note 1)	I <sub>ОН</sub>	$I_F = 250 \mu A,$ $V_O = V_{CC} = 5.5 V$		-	20	250	μA
Lower Level Output Voltage (See notes 1 & 9)	V <sub>OL</sub>	$I_F$ = 10mA, $V_{CC}$ = 5.5V, $I_{OL}$ (sinking) = 10mA		-	0.4	0.6	V
<b>`</b>		$I_F$ = 5mA, V <sub>CC</sub> = 5.5V, $I_{OL}$ (sinking) = 13mA	CD650				
High Level Supply Current	I <sub>CCH</sub>	$V_{CC} = 5.5V, I_{F1} = I_{F2} = 0$		-	15	30	mA
Low Level Supply Current	I <sub>CCL</sub>	$V_{CC} = 5.5V, I_{F1} = I_{F2} = 10mA$	Cs600	-	15	19	mA
			Cd650 Cd651		20	38	
		$V_{CC} = 5.5V, I_{F1} = I_{F2} = 13mA$	Ch350			36	
		$V_{CC} = 5.5V, I_{F1} = I_{F2} = 20mA$	6N134			36	1
Input-Output Insulation Leakage Current (See notes 2 & 10)	I <sub>I-O</sub>	RH = 45%, T <sub>A</sub> = 25°C, t = 5S V <sub>IO</sub> = 1500Vdc		-	-	1.0	μA
Input Forward Voltage (See note 1)	V <sub>F</sub>	I <sub>F</sub> = 10mA, T <sub>A</sub> = 25°C		-	1.5	1.9	V
		I <sub>F</sub> = 20mA		-	-	1.9	
Input Reverse Breakdown Voltage (See note 1)	B <sub>VR</sub>	I <sub>R</sub> = 10μΑ, Τ <sub>Α</sub> = 25°C		5	-	-	V
Propagation Delay Time to High Output Level See notes 1 & 5)	t <sub>PLH</sub>	$R_L = 510\Omega$ , $I_F = 13mA$ , $T_A = 25°C$ , $C_L = 50pF$	6N134	-	-	100	nS
		$R_L = 510\Omega$ , $I_F = 13mA$ , $T_A = 25^{\circ}C$ , $C_L = 15pF$	6N134 CD651	-	60	90	
			CH350			200	
		R <sub>L</sub> = 350Ω, I <sub>F</sub> = 7.5mA, T <sub>A</sub> = 25°C, C <sub>L</sub> = 15pF	Cs600			75	
Propagation Delay Time to Low Output Level (See notes 1 & 6)	t <sub>PHL</sub>	$R_L = 510\Omega, I_F = 13mA,$ $T_A = 25^{\circ}C, C_L = 50pF$	6N134	-	-	100	nS
		R <sub>L</sub> = 510Ω, I <sub>F</sub> = 13mA, T <sub>A</sub> = 25°C, C <sub>L</sub> = 15pF	6N134 CD651	-	55	90	
		$R_L = 510\Omega, I_F = 13mA,$ $T_A = 25^{\circ}C, C_L = 15pF$	CH350			200	1
		$R_L = 350\Omega$ , $I_F = 7.5mA$ , $T_A = 25^{\circ}C$ , $C_L = 15pF$	CS600 CD650			100	1
Current Transfer Ratio (See note 1)	CTR	$I_F = 10mA, V_O = 0.6V, V_{CC} = 5.5V$		100	-	-	%
		$I_F = 5mA, V_O = 0.6V, V_{CC} = 5.5V$	CS600 CD650	100	300		

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## **Typical Characteristics** $T_{A} = 25^{\circ}C$ . $V_{CC} = 5V$ each channel where appropriate

Parameter	Symbol	Test Conditions	Note s	Min	Туре	Max	Units
Input Diode Temperature Coefficient	$\frac{\Delta_{\rm VF}}{\Delta_{\rm TA}}$	I <sub>F</sub> = 20mA	1	-	-1.9	-	mV/°C
Resistance	R <sub>I-0</sub>	V <sub>10</sub> = 500V	3	-	10 <sup>12</sup>	-	Ω
Capacitance	C <sub>I-O</sub>	f = 1MHz	3	-	1.9	-	pF
Input Capacitance	C <sub>IN</sub>	f = 1MHz, V <sub>F</sub> = 0	1	-	60	-	pF
Input-Input Leakage Current	I <sub>I-I</sub>	45% Relative Humidity $V_{II}$ = 500Vdc, t = 5S	4	-	0.5	-	nA
Resistance	R <sub>I-I</sub>	$V_{II} = 500 V dc$	4	-	10 <sup>12</sup>	-	Ω
Capacitance	CI-I	f = 1MHz	4	-	0.6	-	pF
Output Rise (10-90%)	tr	$R_L = 510\Omega, C_L = 15pF, I_F = 13mA$	1	-	35	-	nS
Output Fall Time (90- 10%)	tf	$R_L = 510\Omega, C_L = 15pF, I_F = 13mA$	1	-	35	-	nS
Common Mode Transient Immunity at Logic High Output Level	CM <sub>H</sub>	$V_{O}$ (min) = 2V, $V_{CM}$ = 10V (peak) $R_{L}$ = 510 $\Omega$ , $I_{F}$ = 0mA	1&7	-	1000	-	V/µS
Common Mode Transient Immunity at Logic Low Output Level	CML	$V_O(max) = 0.8V, V_{CM} = 10V (peak)$ $R_L = 510\Omega, I_F = 10mA$	1&8	-	-1000	-	V/µS

#### Notes: (Apply typically to 16 pin package)

1. Each channel, where appropriate.

2. Measured between pins 1 through 4 shorted together, and pins 9 through 16 shorted together.

3. Measured between pins 1 and 2, or 5 and 6 shorted together, and pins 9 through 16 shorted together.

4. Measured between pins 1 and 2 shorted together, and pins 5 and 6 shorted together.

5. The t<sub>PLH</sub> propagation delay is measured from the 6.5mA point on the trailing edge of the input pulse to the 1.5V point on the trailing edge of the output pulse.

6. The t<sub>PHI</sub> propagation delay is measured from the 6.5mA point on the leading edge of the input pulse to the 1.5V point on the leading edge of the output pulse.

7.  $CM_{H}$  is the maximum tolerable common mode transient to assure that the output will remain in a high logic state (i.e.,  $V_{\odot} > 2.0V$ ).

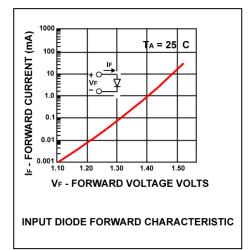
8. CM<sub>L</sub> is the maximum tolerable common mode transient to assure that the output will remain in the logic low state (i.e.,  $V_{\odot} < 2.0V$ ).

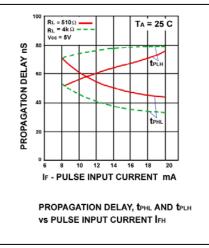
9. It is essential that a bypass capacitor (0.1 to 0.1µF, ceramic) be connected from pin 10 to pin 15. Total lead length between both ends of the capacitor and the isolator pins should not exceed 20mm.

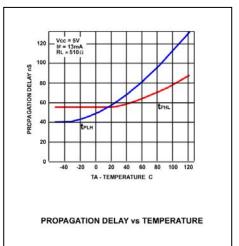
10. This is a momentary withstand test, not an operating condition.

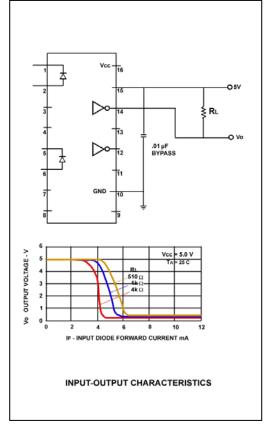
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### **Electrical Characteristics**

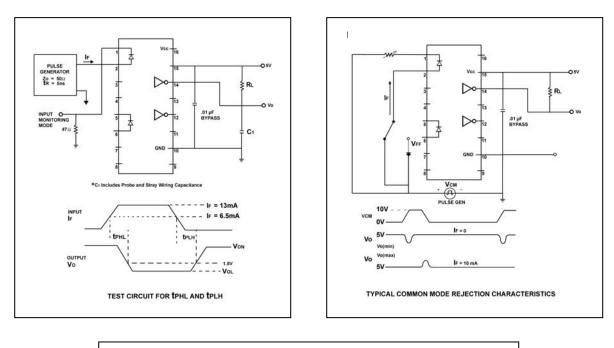


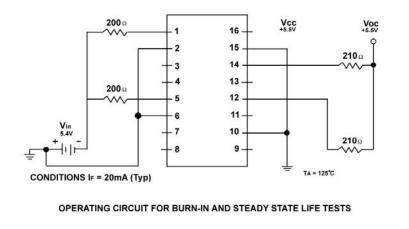






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